

**Preliminary**

TOSHIBA Photocoupler GaAlAs IRED + Photo IC

# TLP350

Industrial Inverter  
 Inverter for Air Conditioner  
 IGBT/Power MOSFET Gate Drive  
 IH(Induction Heating)

Unit: mm

The TOSHIBA TLP350 consists of a GaAlAs light-emitting diode and an integrated photodetector.

This unit is an 8-lead DIP package.

The TLP350 is suitable for gate driving IGBTs or power MOSFETs.

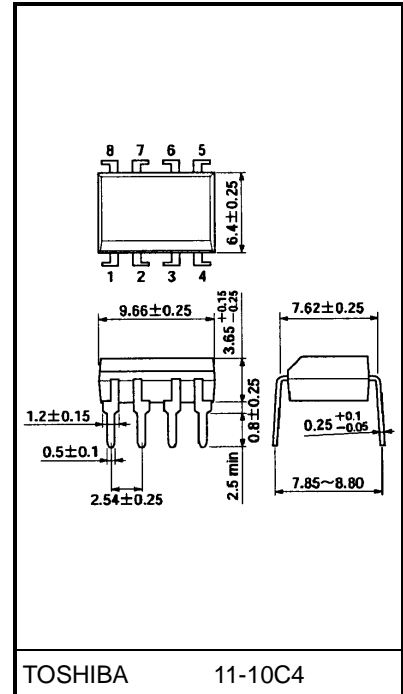
- Peak output current:  $I_o = \pm 2.5A$  (max)
- Guaranteed performance over temperature:  $-40$  to  $100^\circ C$
- Supply current:  $I_{CC} = 2$  mA (max)
- Power supply voltage:  $V_{CC} = 15$  to  $30$  V
- Threshold input current :  $I_{FLH} = 5$  mA (max)
- Switching time ( $t_{pLH}/t_{pHL}$ ) :  $500$  ns (max)
- Common mode transient immunity:  $15$  kV/ $\mu s$
- Isolation voltage:  $3750$  Vrms
- UL Recognized : UL1577, File No. E67349
- Option(D4)

VDE Approved : DIN EN60747-5-2

Maximum Operating Insulation Voltage :  $890V_{PK}$

Highest Permissible Over Voltage :  $4000V_{PK}$

**(Note):When a EN60747-5-2 approved type is needed, Please designate "Option(D4)"**



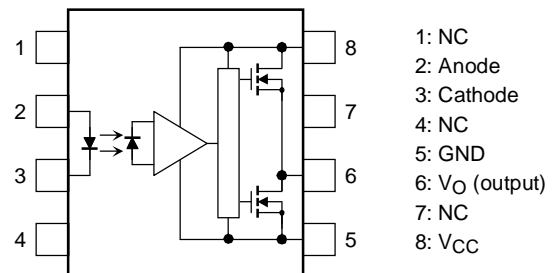
TOSHIBA 11-10C4

Weight: 0.54 g (typ.)

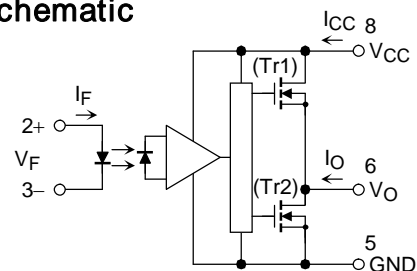
## Truth Table

Input	LED	Tr1	Tr2	Output
H	ON	ON	OFF	H
L	OFF	OFF	ON	L

## Pin Configuration (top view)



## Schematic



A  $0.1 \mu F$  bypass capacitor must be connected between pins 8 and 5. (See Note 6)

## Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
LED	Forward current	$I_F$	20	mA	
	Forward current de-rating (Ta ≥ 85°C)	$\Delta I_F / \Delta T_a$	-0.54	mA/°C	
	Peak transient forward current (Note 1)	$I_{FP}$	1	A	
	Reverse voltage	$V_R$	5	V	
	Junction temperature	$T_j$	125	°C	
Detector	"H" peak output current	$T_a = -40 \text{ to } 100^\circ\text{C}$ (Note 2)	$I_{OPH}$	-2.5	A
	"L" peak output current		$I_{OPL}$	2.5	A
	Supply voltage	$T_a < 95^\circ\text{C}$	$V_{CC}$	35	V
	Supply voltage Derating	$T_a \geq 95^\circ\text{C}$	$V_{CC} / T_a$	-1.0	V /
	Junction temperature		$T_j$	125	°C
Operating frequency (Note 3)	$f$	50	kHz		
Storage temperature range	$T_{stg}$	-55 to 125	°C		
Operating temperature range	$T_{opr}$	-40 to 100	°C		
Lead soldering temperature (10 s) (Note 4)	$T_{sol}$	260	°C		
Isolation voltage (AC, 1 minute, R.H. ≤ 60%) (Note 5)	$BV_S$	3750	Vrms		

Note 1: Pulse width  $P_W \leq 1 \mu\text{s}$ , 300 pps

Note 2: Exponential waveform pulse width  $P_W \leq 0.3 \mu\text{s}$ ,  $f \leq 15 \text{kHz}$

Note 3: Exponential waveform  $I_{OPH} \geq -2.0 \text{A}$  ( $\leq 0.3 \mu\text{s}$ ),  $I_{OPL} \leq 2.0 \text{A}$  ( $\leq 0.3 \mu\text{s}$ )

Note 4: At 2 mm or more from the lead root.

Note 5: This device is regarded as a two terminal device: pins 1, 2, 3 and 4 are shorted together, as are pins 5, 6, 7 and 8.

Note 6: A ceramic capacitor(0.1  $\mu\text{F}$ ) should be connected from pin 8 to pin 5 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypass may impair the switching property.  
The total lead length between capacitor and coupler should not exceed 1 cm.

## Recommended Operating Conditions

Characteristic	Symbol	Min	Typ.	Max	Unit
Input current, ON (Note 7)	$I_F$ (ON)	7.5	—	10	mA
Input voltage, OFF	$V_F$ (OFF)	0	—	0.8	V
Supply voltage	$V_{CC}$	15	—	30	V
Peak output current	$I_{OPH}/I_{OPL}$	—	—	$\pm 2.0$	A
Operating temperature	$T_{opr}$	-40	—	100	°C

Note 7: Input signal rise time (fall time) < 0.5  $\mu\text{s}$ .

## Electrical Characteristics (Ta = -40 to 100°C, unless otherwise specified)

Characteristic	Symbol	Test Circuit	Test Conditions	Min	Typ.*	Max	Unit		
Forward voltage	V <sub>F</sub>	—	I <sub>F</sub> = 10 mA, Ta = 25°C	—	1.6	1.8	V		
Temperature coefficient of forward voltage	ΔV <sub>F</sub> /ΔTa	—	I <sub>F</sub> = 10 mA	—	-2.0	—	mV/°C		
Input reverse current	I <sub>R</sub>	—	V <sub>R</sub> = 5 V, Ta = 25°C	—	—	10	μA		
Input capacitance	C <sub>T</sub>	—	V = 0, f = 1 MHz, Ta = 25°C	—	45	250	pF		
Output current (Note 8)	"H" Level	I <sub>OPH</sub>	1	V <sub>CC</sub> = 30 V, I <sub>F</sub> = 5 mA V <sub>8-6</sub> = -3.5 V	—	-1.6	-1.0	A	
				V <sub>CC</sub> = 15 V, I <sub>F</sub> = 5 mA V <sub>8-6</sub> = -7.0 V	—	—	-2.0		
	"L" Level	I <sub>OPL</sub>	2	V <sub>CC</sub> = 30 V, I <sub>F</sub> = 0 mA V <sub>6-5</sub> = 2.5V	1.0	1.6	—		
				V <sub>CC</sub> = 15 V, I <sub>F</sub> = 0 mA V <sub>6-5</sub> = 7.0V	2.0	—	—		
Output voltage	"H" Level	V <sub>OH</sub>	3	V <sub>CC</sub> 1= +15 V V <sub>EE</sub> 1= -15 V	I <sub>F</sub> = 5 mA	11	13.7	—	V
	"L" Level	V <sub>OL</sub>	4	R <sub>L</sub> = 200	V <sub>F</sub> = 0.8 V	—	-14.9	-12.5	
Supply current	"H" Level	I <sub>CCH</sub>	5	V <sub>CC</sub> = 30 V	I <sub>F</sub> = 10 mA	—	1.3	2.0	mA
	"L" Level	I <sub>CCL</sub>	6	V <sub>O</sub> open	I <sub>F</sub> = 0 mA	—	1.3	2.0	
Threshold input current	L → H	I <sub>FLH</sub>	—	V <sub>CC</sub> = 15V, V <sub>O</sub> > 1V, I <sub>O</sub> = 0mA	—	1.8	5	mA	
Threshold input voltage	H → L	V <sub>FHL</sub>	—	V <sub>CC</sub> = 15V, V <sub>O</sub> < 1V, I <sub>O</sub> = 0mA	0.8	—	—	V	
Supply voltage	V <sub>CC</sub>	—	—	—	15	—	30	V	
UVLO threshold	V <sub>UVLO+</sub>	—	—	V <sub>O</sub> > 2.5 V, I <sub>F</sub> = 5 mA	11.0	12.5	13.5	V	
	V <sub>UVLO-</sub>	—	—		9.5	11.0	12.0	V	
UVLO hysteresis	V <sub>UVLOHYS</sub>	—	—	—	1.5	—	—	V	

\*: All typical values are at Ta = 25°C

Note 8: Duration of I<sub>O</sub> : ≤ 50 μs(1PULSE)

Note 9: This product is more sensitive to static electricity (ESD) than the conventional product because of its minimal power consumption design.

General static electricity precautions are necessary for handling this component.

## Isolation Characteristics (Ta = 25°C)

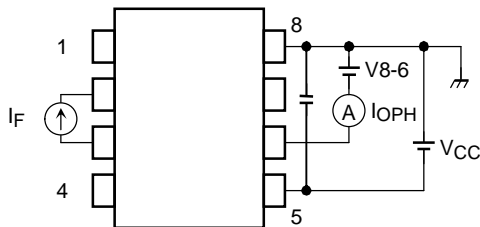
Characteristic	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Capacitance input to output	C <sub>S</sub>	V = 0, f = 1MHz (Note6)	—	1.0	—	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, Ta = 25°C, R.H. ≤ 60% (Note6)	1×10 <sup>12</sup>	10 <sup>14</sup>	—	Ω
Isolation voltage	BV <sub>S</sub>	AC, 1 minute	3750	—	—	V <sub>rms</sub>
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	V <sub>dc</sub>

## Switching Characteristics (Ta = -40 to 100°C, unless otherwise specified)

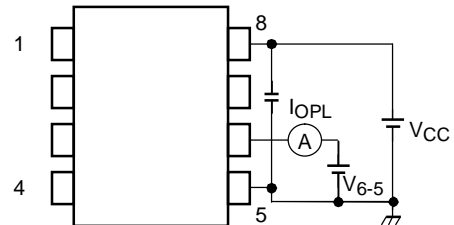
Characteristic	Symbol	Test Circuit	Test Conditions	Min	Typ.*	Max	Unit	
Propagation delay time	L → H	7	V <sub>CC</sub> = 30 V R <sub>g</sub> = 20 Ω C <sub>g</sub> = 10 nF	I <sub>F</sub> = 0 → 5 mA	50	260	500	ns
	H → L			I <sub>F</sub> = 5 → 0 mA	50	260	500	
Switching Time Dispersion between ON and OFF	t <sub>pHL</sub> - t <sub>pLH</sub>	7	V <sub>CC</sub> = 30 V R <sub>g</sub> = 20 Ω, C <sub>g</sub> = 10 nF	—	—	350	ns	
Output rise time (10-90%)	t <sub>r</sub>	7	V <sub>CC</sub> = 30 V R <sub>g</sub> = 20 Ω C <sub>g</sub> = 10 nF	I <sub>F</sub> = 0 → 5 mA	—	15	—	ns
Output fall time (90-10%)	t <sub>f</sub>			I <sub>F</sub> = 5 → 0 mA	—	8	—	
Common mode transient immunity at high level output	CM <sub>H</sub>	8	V <sub>CM</sub> = 1000 V <sub>p-p</sub> Ta = 25°C V <sub>CC</sub> = 30 V	I <sub>F</sub> = 5 mA V <sub>O</sub> (min) = 26V	-15000	—	—	V/μs
Common mode transient immunity at low level output	CM <sub>L</sub>			I <sub>F</sub> = 0 mA V <sub>O</sub> (max) = 1V	15000	—	—	

\*: All typical values are at Ta = 25°C

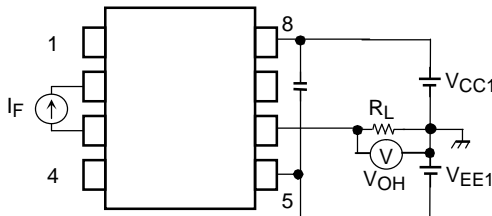
**Test Circuit 1: I<sub>OPH</sub>**



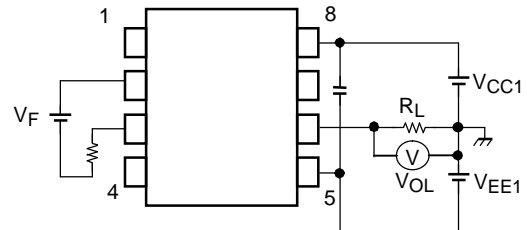
**Test Circuit 2: I<sub>OPL</sub>**



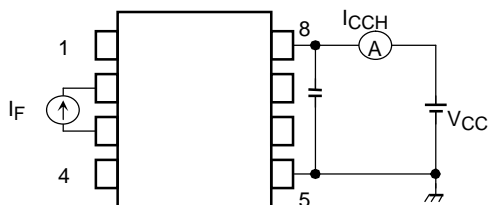
**Test Circuit 3: V<sub>OH</sub>**



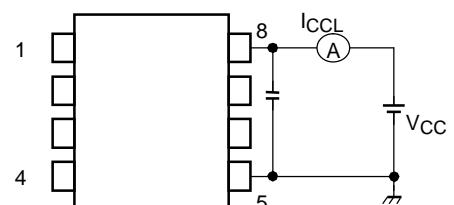
**Test Circuit 4: V<sub>OL</sub>**



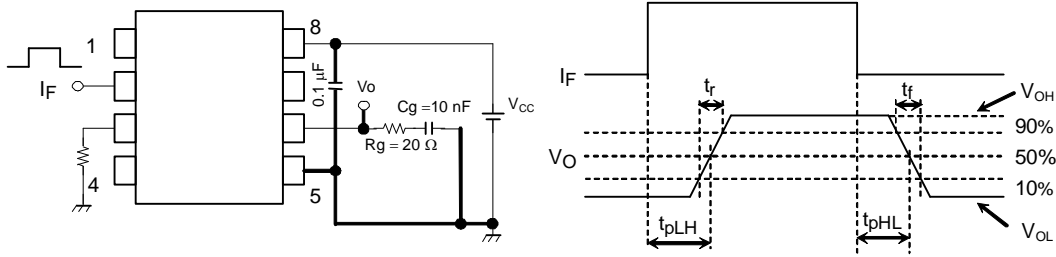
**Test Circuit 5: I<sub>CCH</sub>**



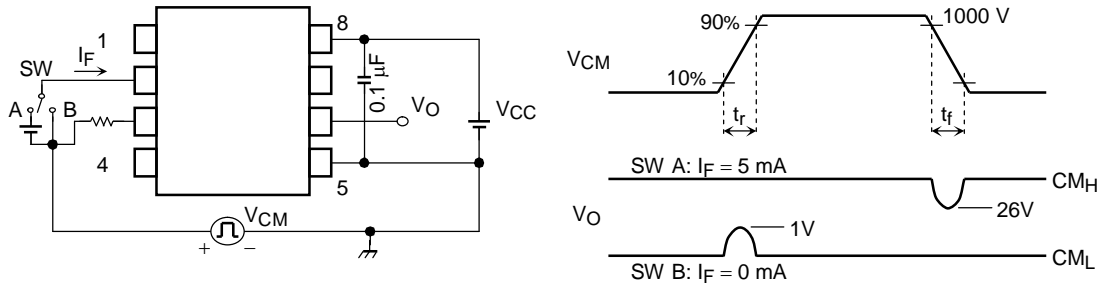
**Test Circuit 6: I<sub>CCL</sub>**



**Test Circuit 7:  $t_{pLH}$ ,  $t_{pHL}$ ,  $t_r$ ,  $t_f$ , PDD**

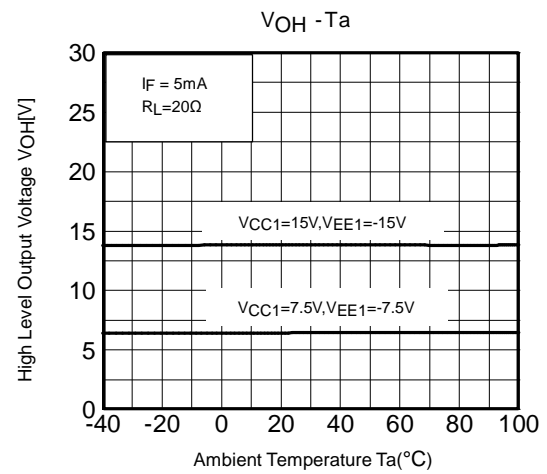
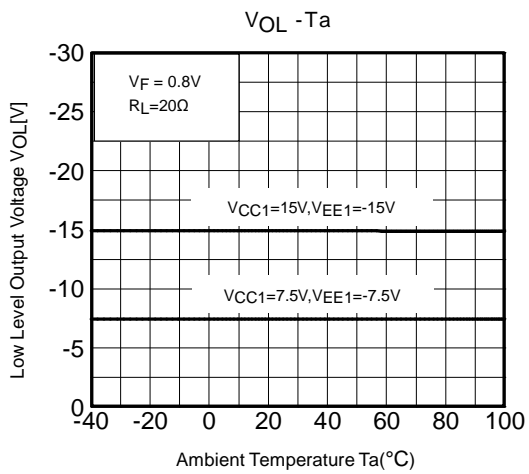
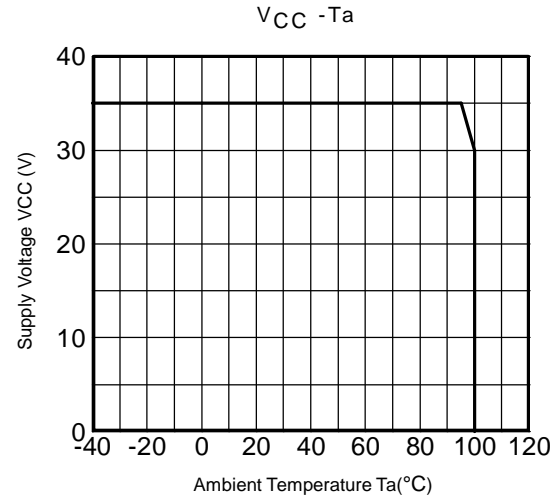
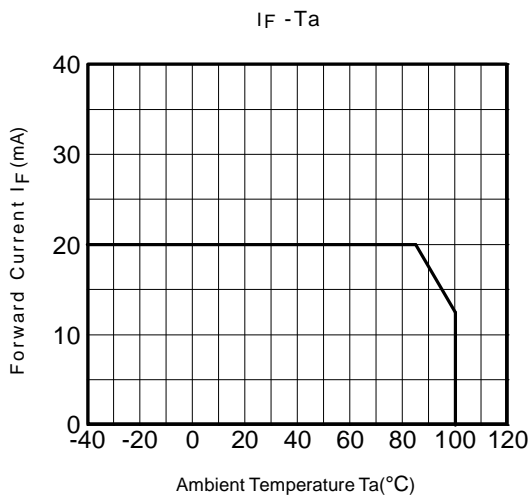
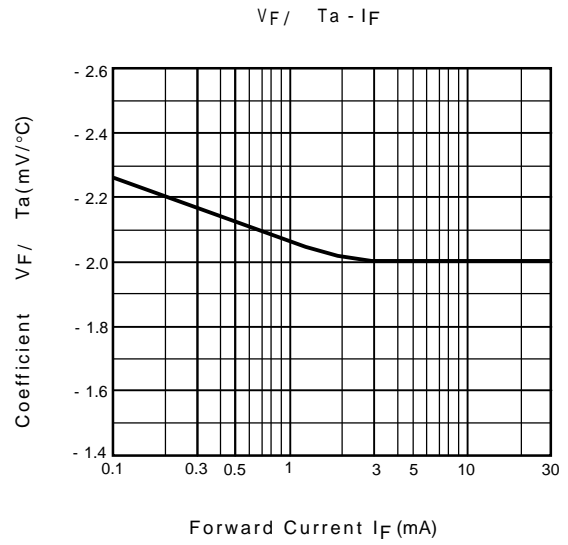
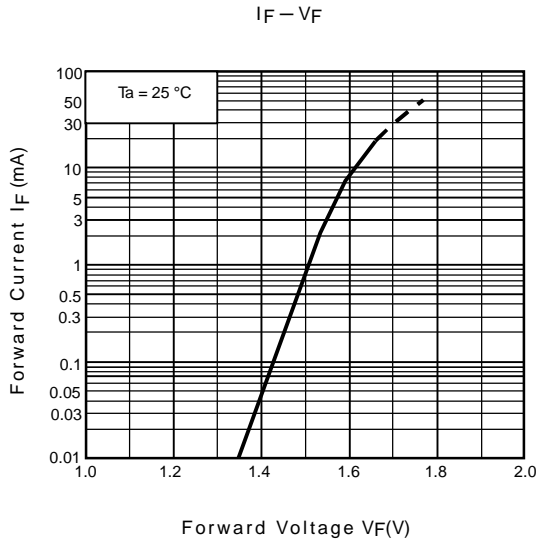


**Test Circuit 8:  $CM_H$ ,  $CM_L$**

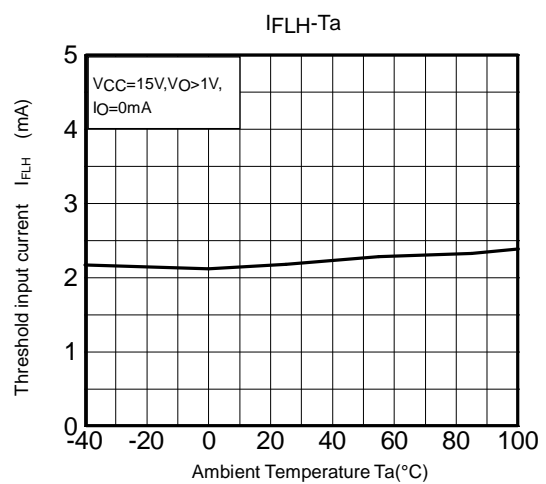
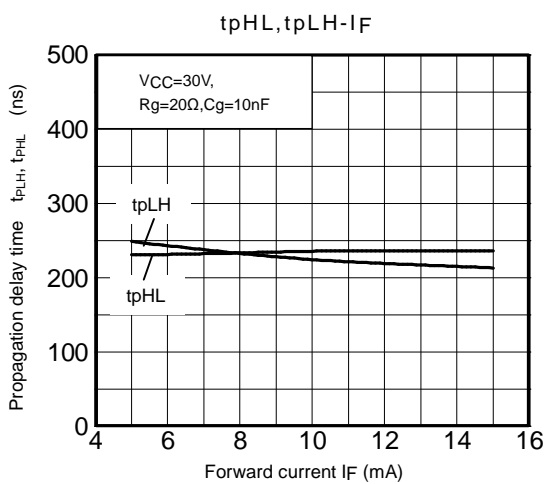
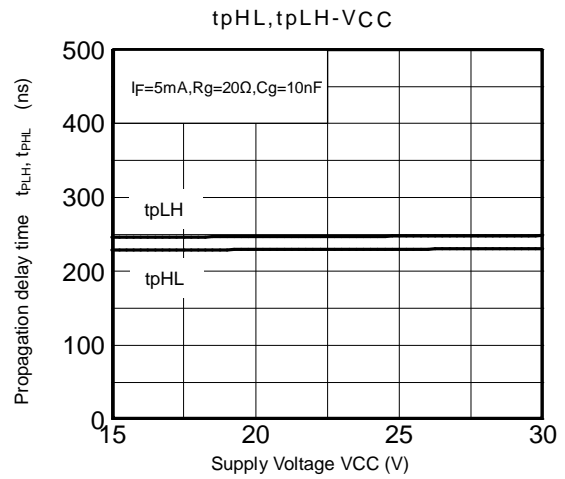
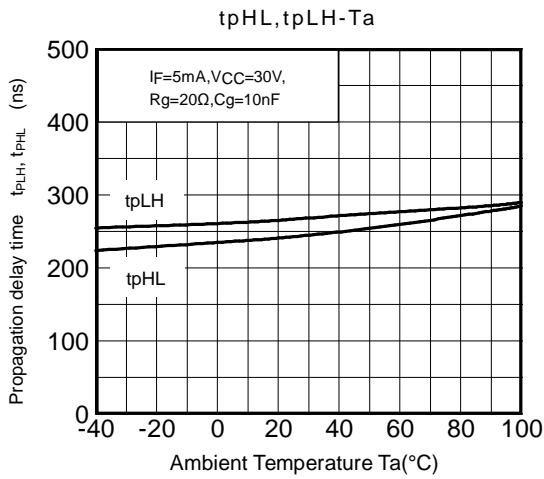
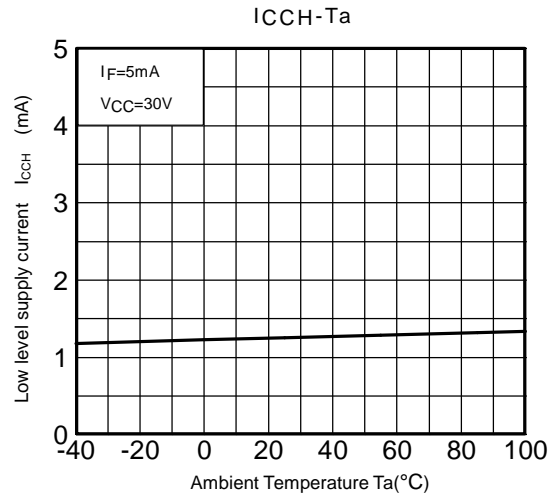
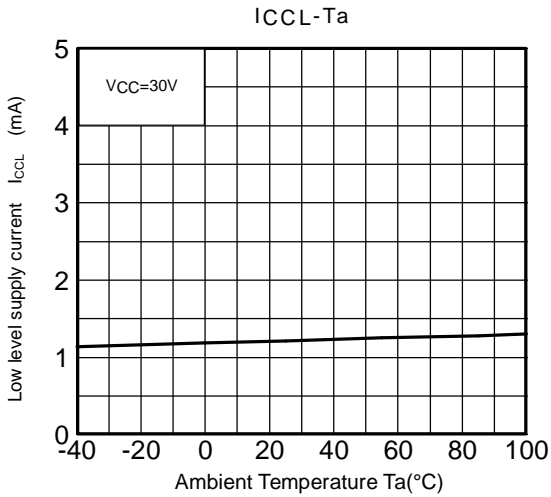


$$CM_L = \frac{800(V)}{t_r (\mu s)} \quad CM_H = \frac{800(V)}{t_f (\mu s)}$$

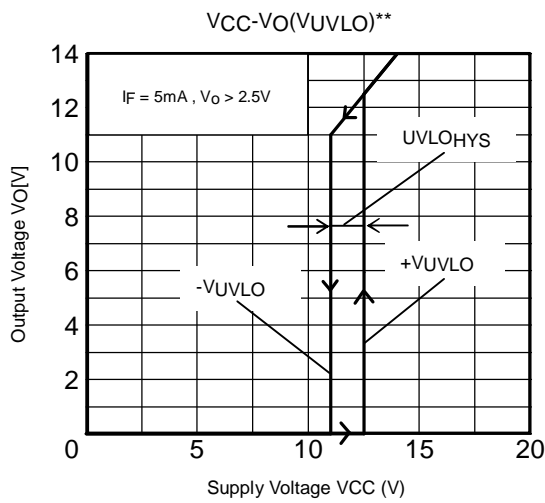
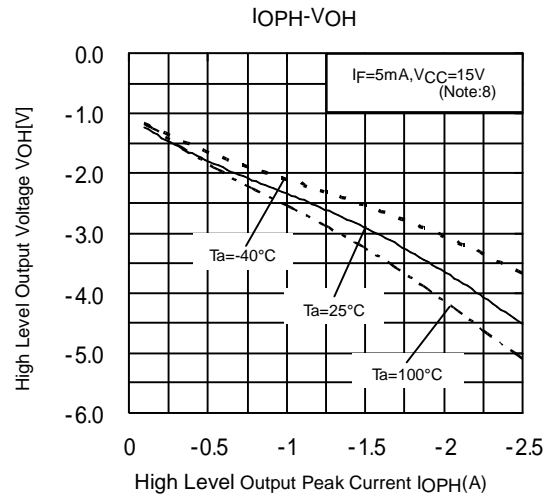
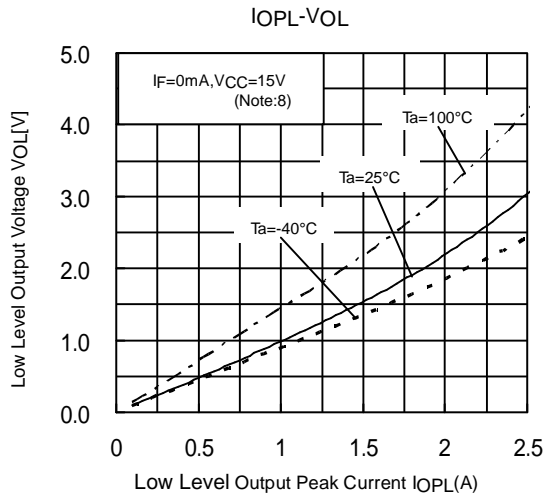
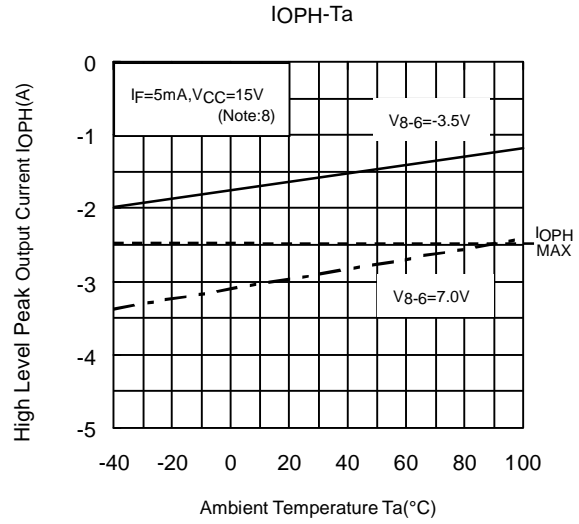
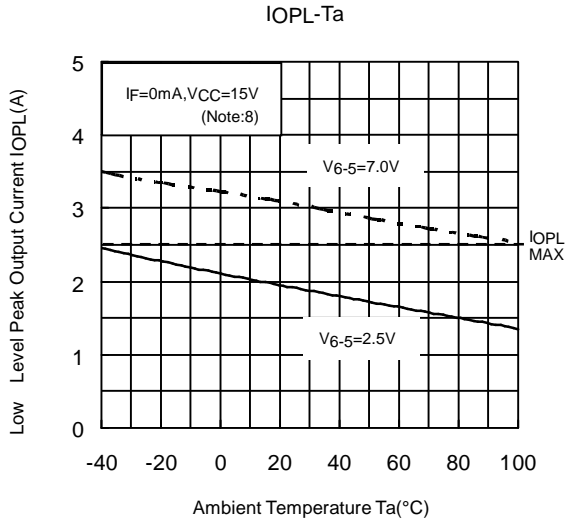
$CM_L$  ( $CM_H$ ) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.



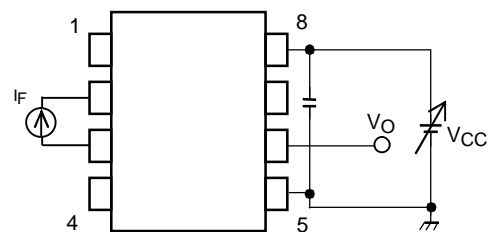
\*: The above graphs show typical characteristics.



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\*\*Test Circuit : V<sub>CC</sub>-V<sub>O</sub>(V<sub>UVLO</sub>)



\*: The above graphs show typical characteristics.



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